

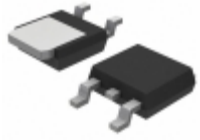



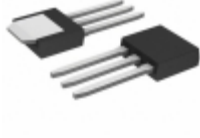
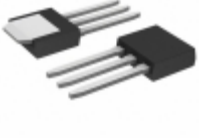

	<b>NTD65N03RT4G</b>
	<b>Hersteller-Teilenummer:</b> NTD65N03RT4G
	<b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b> MOSFET N-CH 25V 9.5A DPAK
	<b>Datenblätter:</b>  <a href="#">NTD65N03RT4G.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 7500 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
	<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

**Spezifikationen**

Teilenummer	NTD65N03RT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 9.5A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	7500 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.3W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9.5A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	8.4 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1400pF @ 20V
Verpackung	Tape & Reel (TR)

NTD65N03RT4G ist neu im Original, Suche NTD65N03RT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD65N03RT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD65N03RT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>NTD6600NT4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p><b>NTD6600G</b> ON NTD6600G ON</p>	 <p><b>NTD65N03R-35G</b> VB NTD65N03R-35G VB</p>	 <p><b>NTD65N03RG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A DPAK</p>
 <p><b>NTD6600N-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A IPAK</p>	 <p><b>NTD65N03R-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A IPAK</p>	 <p><b>NTD65N03R-035</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A IPAK</p>	 <p><b>NTD6600N-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A IPAK</p>

**heiße Teile**

Mehr

- |                 |                 |                 |                 |                |
|-----------------|-----------------|-----------------|-----------------|----------------|
| ⊗ NTD60N03RT4G  | ↔ NTD60N03T4    | ⇒ NTD60N03T4G   | D NTD6414AN     | ↔ NTD6414AN-1G |
| ⊣ NTD6414ANT4G  | ⊗ NTD6414AUG    | D NTD6415AN     | ⇒ NTD6415AN-1G  | ↔ NTD6415ANL   |
| ⊗ NTD6415ANLT4G | ⊣ NTD6415ANT4G  | ⊗ NTD6416AN     | ↔ NTD6416AN-1G  | ↔ NTD6416ANG   |
| D NTD6416ANL    | ⊗ NTD6416ANL-1G | ⊣ NTD6416ANLT4G | ⊗ NTD6416ANT4G  | ↔ NTD65N03G    |
| ⇒ NTD65N03R-001 | ↔ NTD65N03R-035 | ⊗ NTD65N03R-1G  | ⊣ NTD65N03R-35G | ↔ NTD65N03RG   |
| ↔ NTD6600G      | ⇒ NTD6600N      | D NTD6600N-001  | ⊗ NTD6600N-1G   | ⊣ NTD6600NT4   |
| ⊗ NTD6600NT4G   | D NTD70N03      | ⇒ NTD70N03R     | ↔ NTD70N03R-001 | ↔ NTD70N03R-1  |
| ⊣ NTD70N03R-1G  | ⊗ NTD70N03RG    | ↔ NTD70N03RT4   | ⇒ NTD70N03RT4G  | ↔ NTD70N03TR4  |
| ⊗ NTD78N03      | ⊣ NTD78N03-001  | ⊗ NTD78N03-035  | D NTD78N03-1    | ↔ NTD78N03-1G  |
| ↔ NTD78N03-35G  | ⊗ NTD78N03R-001 | ⊣ NTD78N03R-1G  | ⊗ NTD78N03RT4G  | ↔ NTD78N03T4   |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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